Contents

numbers 1-3

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AUTHORS		ARTICLES
Surface Science Section		
A M Bradshaw, K Hermann and D P Woodruff	3	Preface
		Plenary Lecture
E Bauer, M Mundschau, W Swiech and W Telieps	5	Low energy electron microscopy of surface processes
K Ueda and A Takano	11	Initial oxidation study of titanium by dynamic measurement of T-O-F, electron stimulated desorption
G W R Leibbrandt, P C Görts, S Deckers, F H P M Habraken and W F van der Weg	13	Oxidation of Pt covered Fe(100) surfaces
A Chiorino, G Ghiotti and F Boccuzzi	16	Reactivity and electronic properties of two microcrystalline ZnO surfaces: interaction with CO and CO/O_2
F J Bustillo, E Román and J L de Segovia	19	Independence of the population of OH radicals from dissociated water on the number of Ti^{+3} point defects of $TiO_2(001)$ surface at 250 K
S Kennou, M Kamaratos and C A Papageorgopoulos	22	Potassium adsorption on NiO(100)
M Ushio, S Higuchi, M Asano, H Misaki and Y Nakanishi	25	The study of rare-earth metal oxidation by AES
A G Akimov and N A Melnikova	28	The study of selective oxidation of copper–aluminium alloy
J K N Sharma, B R Chakraborty and S M Shivaprasad	31	The role of Ti 3d electrons in the formation of titanium silicide and oxide
H Kuhlenbeck, G Odörfer, R Jaeger, C Xu, T Mull, B Baumeister, G Illing, M Menges,H-J Freund, D Weide, P Andresen, G Watson and E W Plummer	34	Adsorption, thermal and photochemical reactions of NO on clean and oxygen precovered Ni(100) surfaces
G Spoto, C Morterra, L Marchese, L Orio and A Zecchina	37	The morphology of TiO_2 microcrystals and their adsorptive properties towards CO: a HRTEM and FTIR study
E Román, F J Bustillo and J L de Segovia	40	Adsorption of methanol on the low Ti^{+3} point defects of the $TiO_2(001)$ surface at 300 K
L A Vasilyev, A P Dementjev and V I Rakhovsky	43	The dissociation of transition metal oxides under exposure to low energy ions
N Bickel, G Schmidt, K Heinz and K Müller	46	Structure determination of the $SrTiO_3(100)$ surface
F P Netzer	49	Determination of structure and orientation of organic molecules on metal surfaces
S Rey, I Colera and J L de Segovia	54	ESD and TDS study of the adsorption of methanol on Nb(110)

E Yagasaki, A L Backman and R I Masel	**57**	The adsorption and decomposition of ethylene on Pt(210), (1 × 1)Pt(110) and (2 × 1)Pt(110)
W K Walter, R G Jones and K C Waugh	**60**	1, 2-Dichloroethane adsorption on Cu(111) using LEED and AES
H Moritz and H Lüth	**63**	Interactions in the coadsorption system CO/acetonitrile on Pt(111): an IRAS investigation
S Yamamoto, R M Lewis, H Hotta and H Kuroda	**65**	Photochemical grafting of metal carbonyl clusters to inorganic oxides
M Beckschulte, D Mehl and E Taglauer	**67**	The adsorption of CO and Ni(100) studied by low energy ion scattering
Y J Chabal	**70**	Molecular diffusion on metal surfaces: time-resolved infrared spectroscopy and other techniques
J G Chen, W Erley and H Ibach	**74**	Significant N–O bond strengthening upon the interaction of NO with coadsorbed oxygen on Ni(111)
M Bertolo, K Jacobi, S Nettesheim, M Wolf and E Hasselbrink	**76**	Adsorption of NO on Pd(111)
W Arabczyk, T Baumann, H-J Müssig, F Storbeck and A Meisel	**79**	Interaction between sulphur and oxygen on Fe(111)
M Kiskinova, A Szabo and J T Yates	**82**	Dynamical effects during CO-induced phase transformation in p(2 × 2)S and p(2 × 2)Se overlayers on Pt(111)
D A Wesner	**85**	X-ray photoelectron diffraction: a sensitive probe of adsorbate and surface structure
C Westphal, J Bansmann, M Getzlaff and G Schönhense	**87**	Experimental observation of circular dichroism in photoemission
S Sugai, H Watanabe, H Miki, T Kioka and K Kawasaki	**90**	Chemisorption of NO on Pd single crystals studied by UPS, AES and XPS
G Wedler, W Kießling and D Borgmann	**93**	Influence of coadsorption of oxygen on adsorption of CO_2 on Fe(111)
S Bogen, H Hoinkes, E Poehlmann and H Wilsch	**96**	SSIMS study of CO_2 adsorption and reactions on clean and oxygen covered Ni(110)
J Ahner, A Effendy, K Vajen and H-W Wassmuth	**98**	Chemisorption and multilayer adsorption of SO_2 on Ag(111) and Ag(110)
M Höfer, S Hillig and H-W Wassmuth	**102**	Improvement of the Kelvin method by overtone detection and application to adsorption and desorption studies of SO_2 on Pt(111)
H Miki, K Takeuchi, T Kioka, S Sugai and K Kawasaki	**105**	Chemisorption of NO on Pt(410) surface studied by AES, UPS and XPS
M Volkmer, K Nolting, G H Fecher, B Dierks and U Heinzmann	**109**	Experimental studies of the adsorption of oxygen and nitric oxide at Ni(100)
J Lahtinen, J Vaari, A Talo, A Vehanen and P Hautojärvi	**112**	Adsorption and desorption measurements of CO and O_2 on cobalt
T Yamada, J Siera, H Hirano, B E Nieuwenhuys and K Tanaka	**115**	HREELS study of the Pt–Rh(100) alloy single crystal surface during NO + H_2 reaction
S Chiang, R J Wilson, C M Mate and H Ohtani	**118**	Observations of domain boundaries and steps on the Rh(111)–c($2\sqrt{3}$ × 4)rect (C_6H_6 + CO) surface by scanning tunneling microscopy
L Hammer, B Dötsch, C Harder and K Müller	**121**	On the kinetics of hydrocarbon decomposition on the Ni(111) surface—a time-resolved HREELS study
B M Shipilevsky and V G Glebovsky	**126**	Competition of bulk and surface processes in the kinetics of hydrogen and nitrogen release from metals into vacuum
B Sente, M Dumont and R Dagonnier	**130**	Fractal kinetics in surface reactions

H Hirano, T Yamada, K Tanaka, J Siera and B E Nieuwenhuys	**134**	Dynamical behaviour of Pt–Rh(100) alloy surface upon NO dissociation and NO + H_2 reaction
M Eriksson, L Hultman and L-G Petersson	**137**	The water-forming reaction on thin, SiO_2 supported, palladium films
H-H Angermann and G Hörz	**139**	Decarburization kinetics as a probe for studying carbon-induced and sulfur modified surface structural changes on nickel and Ni–Cr alloys
M W Rophael, L B Khalil and M M Moawad	**143**	The reduction of aqueous carbonate to methanol, photocatalysed by TiO_2 phthalocyanine
A Berkó, F P Coenen and H P Bonzel	**147**	Structure sensitivity of methanation on nickel
N Rösch, A Görling, P Knappe and J Lauber	**150**	On the alkali-induced vibrational frequency shift of CO chemisorbed on transition metal surfaces
J Hrbek, G-Q Xu, T K Sham and M-L Shek	**153**	Interaction of potassium overlayers with oxygen and a potassium–dioxygen surface complex with carbon monoxide
D Ehrlich, S Wohlrab, J Wambach, H Kuhlenbeck and H-J Freund	**157**	Reaction of CO_2 and Pd(111) activated via promotor action of alkali coadsorption
A Cassuto, M Touffaire, M Hugenschmidt, P Dolle and J Jupille	**161**	Ethylene π-species on bare and K-, Cs- and O-precovered Pt(111): a TDS and UPS study
J Noffke, B Weimert and L Fritsche	**163**	Electronic structure calculations on Cu(110) and Ni(110) films with p(2 × 1) oxygen overlayers
E Schwarz, J Lenz, H Wohlgemuth and K Christmann	**167**	The interaction of oxygen with a rhodium (110) surface
A P Dementjev and O P Ivanova	**171**	LVV Auger structure of sulphur, segregated on 3d metals and alloy surfaces
P Dolle, P Louis and J Jupille	**174**	On the ability of Cs- and Na-precovered Ni(111) surfaces to form dioxygen species upon oxygen exposure
I Arakawa, H Sato and S Yamane	**177**	Precision measurement of the equilibrium pressure of krypton adsorbed on exfoliated graphite in the region close to the bulk saturation vapour pressure
E Schwarz, K H Ernst, C Gonser-Buntrock, M Neuber and K Christmann	**180**	Ordered oxygen phases on a Co($10\bar{1}0$) surface
T A Sasaki, Y Baba and H Yamamoto	**185**	Nitridation induced on metal surface by Ar^+-ion impact under N_2 atmosphere
L Stauffer, R Riedinger and H Dreyssé	**188**	Trio interaction energies between hydrogen atoms near a metallic surface
B Gumhalter, K Hermann and K Wandelt	**192**	Lateral surface Stark effect in chemisorbed molecules
P M Stoop, J H van der Merwe and M W H Braun	**195**	Description of adsorption phenomena within the framework of the embedded atom method
P Mrozek, D Kaletta, A E Reynolds and K Wandelt	**199**	Monte Carlo simulation of temperature programmed desorption of Ag atoms from a Ru(001) surface
G P Brivio, T B Grimley, V Bortolani, A Franchini and G Santoro	**202**	Vibrational effects in desorption of light rare gases from metals
H F Arlinghaus, W F Calaway, C E Young, M J Pellin, D M Gruen and L L Chase	**204**	Isotope shifts of Zn neutral atoms measured by two-photon Doppler-free laser-induced fluorescence spectroscopy
J Heidberg, B Brase, W Claas and H-C Langowski	**207**	CO_2 laser-induced desorption of benzotrifluoride from NaCl(100) and C-film–NaCl(100)

U Diebold and P Varga	**210**	Determination of cross-sections for CO desorption from Ni(111) induced by Ar-ions of very low impact energy
T Gotoh, S Takagi and G Tominaga	**213**	Observation of ion desorption from MgO(001) by electron bombardment
H Daimon and S Ino	**215**	ESDIAD with a new display-type spherical mirror analyser
M Sakurai, T Hirayama and I Arakawa	**217**	Time-of-Flight measurement of desorbed particles from solid rare gases using synchrotron radiation
S L Bennett and E M Williams	**220**	An ESD study of the initial stages of oxide formation at the Si–H_2O interface
I Colera, S Rey and J L de Segovia	**224**	EELS and AES transitions study of clean and O, C, H_2O and CH_3OH contaminated Nb(110) surfaces
B Oral and R W Vook	**227**	Thermal desorption spectroscopy of CO adsorption on epitaxial Cu(111)-Pd(111) thin film surfaces
K Nagai	**230**	Theoretical study of layer by layer zero-order desorption rate
A M de Jong and J W Niemantsverdriet	**232**	Comparative test of procedures for thermal desorption analysis
M Sakurai, T Okano and Y Tuzi	**234**	Surface resonances in a CH_4 monolayer physisorbed on a silver (111) surface
W Wurth and J Stöhr	**237**	Model calculations for molecular photoabsorption spectra
T S Jones and N V Richardson	**240**	The angular behaviour of electrons inelastically scattered from the shape resonance for CO chemisorbed on Ni(110)
M D Crapper and D P Woodruff	**244**	Intramolecular and multiple scattering in SEXAFS of an adsorbed small molecule
A W Kleyn	**248**	Orientation and harpooning in molecule–surface collisions
S Schubert, U Imke and W Heiland	**252**	Negative molecular state formation and dissociation of molecules scattered from Ni(111) and Ni(111) + K surfaces
R J MacDonald, D J O'Connor and T Wiklendt	**255**	The scattering of low-energy atomic and molecular ions from solid surfaces
L Schröter, R David and H Zacharias	**257**	State selective investigation of recombinative D_2 and HD desorption from Pd(100) and Au/Pd(100)
P Cremaschi, G F Tantardini, J Muilu and T A Pakkanen	**260**	Adsorption of hydrogen on zinc—calculation of potential energy surface and dynamics
G H Fecher, M Volkmer, B Pawlitzky, N Böwering and U Heinzmann	**265**	Orientation dependence of the sticking probability of NO at Ni(100)
M Asscher, G Haase and R Kosloff	**269**	Tunneling mechanism for the dissociative chemisorption of N_2 on metal surfaces
M Sander, M R Bassett, R Imbihl and G Ertl	**272**	Spatial coupling between kinetic oscillations on different regions of a cylindrical Pt single crystal
T Matsushima	**275**	Crystal azimuth dependence of the desorption flux of carbon dioxide produced on palladium (110) and (111) surfaces
G A Cordonier, F Schüth and L D Schmidt	**278**	Decomposition of CH_3NH_2 on Pt and Rh: rate oscillations and surface intermediates
J M White, S Hatch, X-Y Zhu and A Campion	**282**	Surface photochemistry—13. UV-photochemistry of adsorbed O_2 on Pt(111)
R Franchy, S K So and W Ho	**284**	Photodesorption of NO on Ag(111) at 80 K
E Hasselbrink, S Nettesheim, M Wolf, A Cassuto and G Ertl	**287**	Laser induced dissociation of NO_2 adsorbed on Pd(111)
Xueying Shen	**289**	Corrugation effect on the dynamic process of the molecule–surface interaction

K Christmann, G Lauth and E Schwarz	**293**	Adsorption geometry of H on Ru(10$\bar{1}$0) as determined by LEED and HREELS
W Nichtl-Pecher, W Oed, H Landskron, K Heinz and K Müller	**297**	Reconstructive adsorption of H–Rh(110)—a multiphase study
Th Fink, J-P Dath, M R Bassett, R Imbihl and G Ertl	**301**	A new model for the 'explosive' NO + CO reaction on Pt(100)
P Gardner, M Tüshaus, R Martin and A M Bradshaw	**304**	The lifting of the Pt{100} surface reconstruction by NO adsorption
A Bartolini, F Ercolessi and E Tosatti	**307**	Magic vicinal surfaces induced by reconstruction
T Gustafsson, P Fenter and P Häberle	**309**	Determination of the geometric structure of alkali induced reconstructions of Au(110)
B Legrand, M Guillopé, J S Luo and G Tréglia	**311**	Multilayer relaxation and reconstruction in bcc and fcc transition and noble metals
G Varga and L Füstöss	**315**	Surface reconstruction by simple hard corrugated wall model computations
K Kern, I K Robinson and E Vlieg	**318**	The high temperature phase transition of Pt(110) (1 × 2)
M Borbonus, O Haase, R Koch and K H Rieder	**321**	Comparative LEED and STM study of Au(430)
G Hilgers, U Kleineberg, K Nolting, S Wirth, N Müller and U Heinzmann	**325**	Spin-polarized LEED from Xe-Pt(111)
K Heinz	**328**	Diffuse intensities in LEED
A Atrei, U Bardi, G Rovida, E Zanazzi and G Casalone	**333**	Test of structural models for Cu(001)–($\sqrt{2} \times 2\sqrt{2}$)R45°–O by LEED intensity analysis
F Jensen, I Stensgaard, F Besenbacher and C Klink	**337**	Oxygen on Ni(100): is there an asymmetric adsorption site?
J B Pendry, K Heinz and W Oed	**340**	Direct methods in surface crystallography
U Korte and G Meyer-Ehmsen	**343**	Transmission features in RHEED from flat surfaces
K Hermann	**346**	Computer based visualization of channelling directions at single crystal surfaces
P Martin, P v Blanckenhagen, U Romahn and W Schommers	**349**	The role of the Renninger effect in low energy electron diffraction
T Yikegaki, H Sibata, K Takada, S Takatoh, T Fujikawa and S Usami	**352**	EXELFS of vanadium carbide with primary electrons of a few keV
M De Crescenzi, R Diamanti, L Lozzi, M Passacantando, P Picozzi and S Santucci	**356**	A structural investigation on evaporated small clusters of Cr by surface electron energy loss fine structure spectroscopy
R Zimny, H Nienhaus and H Winter	**359**	Parametrization of neutralization of fast ions at surfaces
K J Snowdon, D J O'Connor, M Kato and R J MacDonald	**363**	Skipping motion and adsorption of low velocity ($v \ll v_{Fermi}$) ions on metal surfaces
U van Slooten, T C M Horn and A W Kleyn	**366**	Angular distributions in Na scattering from clean and Cs-covered Ag(111)
J Murakami, T Hashimoto and I Kusunoki	**369**	Ion scattering and surface recoiling from a Si surface by low energy Ne^+ bombardment
E van de Riet, J M Fluit and A Niehaus	**372**	Determination of the surface Debye temperature with LEIS
H Dürr, R Schneider and Th Fauster	**376**	Thermal vibrations at copper surfaces studied by low energy ion scattering
N Barniol, E Farrés, F Martin, J Suñé, I Placencia and X Aymerich	**379**	Simple STM theory

U Dürig and O Züger	**382**	Study of metallic adhesion using scanning tunneling microscopy
R Wiesendanger, G Tarrach, D Bürgler, T Jung, L Eng and H-J Güntherodt	**386**	An ultrahigh vacuum scanning tunneling microscope for surface science studies
K Kern	**389**	Critical phenomena and defects in physisorbed layers
G R Castro, H Isern, U Schneider, M Stöcker and K Wandelt	**393**	Xenon adsorption on NiAl(110)
K Bärwinkel and S Schippers	**396**	Accommodation in Ar(Kr, Xe) and metal–surface systems as a test for electronic dissipation
J Jupille, J J Ehrhardt, D Fargues and A Cassuto	**399**	A SEXAFS evidence for an incommensurate xenon overlayer on a Cu(111) surface
H Shechter, R Brener and J Suzanne	**401**	Dynamical properties of physisorbed monolayers: Mössbauer studies
M Bienfait, J M Gay and P Zeppenfeld	**404**	Surface melting of thin films of methane
X J Chen, F Ercolessi, A C Levi, E Tosatti and A Trayanov	**406**	Surface supermelting with long-range potential
C Stuhlmann, U Beckers, M Wuttig, H Ibach and G Schmidt	**408**	Order–disorder transition of two-monolayer Fe films on the Cu(100) surface
W Schleıer, G Besold and K Heinz	**412**	Structure transition kinetics and surface defects—a Monte Carlo study
K P Bohnen and K M Ho	**416**	Structure and dynamics at metal surfaces
B Voigtländer, S Lehwald and H Ibach	**422**	Phonon dispersion on Au(110)—EELS results compared to 'glue'-model and first principles calculations
F Fabre, G Armand, J R Manson and J Lapujoulade	**424**	Surface vibrational properties in the presence of defects and adsorbates
V Bortolani, A Franchini, G Santoro, F Ercolessi and E Tosatti	**428**	Explanation of the surface force constant softening: the case of Au(111)
U Höfer, M J Breitschafter and E Umbach	**431**	Information from vibration-resolved uv photoemission spectra of physisorbates
M Wuttig, W Hoffmann, E Preuß, R Franchy and H Ibach	**433**	Structure and dynamics of NiAl(110)
U Bardi, A Atrei, E Zanazzi, G Rovida and P N Ross	**437**	Study of the reconstructed (001) surface of the $Pt_{80}Co_{20}$ alloy
G Tréglia, B Legrand and F Ducastelle	**441**	On the temperature dependence of the surface sandwiches observed in PtNi and AgNi alloys
H Dreyssé, G Ceder, D de Fontaine and L T Wille	**446**	Determination of effective pair interactions and segregation behavior at alloy surfaces
M C Zonnevylle, T Rhodin, K Wandelt, B Konrad and T Weser	**449**	Valence band structure of monolayer alloy films of copper and gold on Ru(0001)
L Z Mezey, J Giber, W Hofer, P Novacek and P Varga	**453**	The influence of environmental parameters on solid surface composition
Y Teraoka	**457**	Order–disorder transitions in binary alloys with the fcc(100) surface
C Krembel, M C Hanf, P Wetzel, C Pirri, J C Peruchetti, D Bolmont and G Gewinner	**460**	Photoemission investigation of the initial growth mode of Cr on Ag(100)
S Ferrer and J J de Miguel	**464**	Epitaxial growth of metals studied with thermal energy atom scattering
J E Parmeter, R Kunkel, B Poelsema, L K Verheij and G Comsa	**467**	Morphology of a Pt(111) surface during its growth from the vapor phase

W-Y Leung, P J Schmitz and P A Thiel	**471**	Pt and Au films grown on Pd(110): dependence of (1 × 2) and (1 × 3) reconstructions on deposition temperature and film thickness
H Grabhorn and A Otto	**473**	What determines the selection rules of surface-enhanced Raman spectroscopy?
F Sabary and J C Dudek	**476**	Enhanced photoemission from resonant granular silver films deposited on metallic substrates
J W Evans	**479**	Modelling of epitaxial thin-film growth on fcc(100) substrates at low temperatures
A Cebollada, J M Gallego, J J de Miguel, R Miranda, J L Martinez, S Ferrer, G Fillion and J P Rebouillat	**482**	Epitaxial growth of metals: from monolayer to superlattice
H Poppa, D Fargues, L Kieken, D Neiman and R Savoy	**485**	The sticking coefficient of Pd on planar alumina supports
H P Oepen, M Benning, C M Schneider and J Kirschner	**489**	Magnetic domain structure in ultrathin ferromagnetic films
J Kirschner and J Hartung	**491**	Study of the near-surface Stoner excitation in O- and CO-covered Ni(110) by inelastic electron scattering
W Heinen, C Carbone, T Kachel and W Gudat	**493**	Electronic structure and magnetism of epitaxial Fe monolayers on Au(001) by spin-polarized photoelectron spectroscopy
C Carbone, R Rochow, L Braicovich, R Jungblut, T Kachel, D Tillmann and E Kisker	**496**	Spin-resolved photoemission study of the electronic and magnetic coupling between rare earth adatoms and the Fe(001) surface
M S Hammond, G Fahsold, K Koike and J Kirschner	**500**	Spin-dependence of absorbed and reflected current on Fe(110) and a comparison with secondary electron polarization fine structure
C M Schneider, P Bressler, P Schuster, J Kirschner, J J de Miguel, R Miranda and S Ferrer	**503**	Epitaxy and magnetic properties of fcc cobalt films on Cu(100)
G Schönhense	**506**	Spin-dependent effects in photoemission
C M Schneider, G S Sohal, P Schuster and J Kirschner	**511**	Spin polarised angle resolved uv photoelectron spectroscopy study of $Cu_3Au(001)$ using circularly polarised synchrotron radiation
W Hübner and K-H Bennemann	**514**	Theory of non-linear surface magneto-optics for ferromagnetic nickel
J Kirschner, K Koike and H P Oepen	**518**	Spin polarization of ion excited secondary electrons from ferromagnets
J Voigt, R Fink, G Krausch, B Luckscheiter, R Platzer, R Wesche, U Wöhrmann, X L Ding and G Schatz	**521**	Monolayer-resolved magnetic and electric hyperfine fields at Ni(111) surfaces
Daoxuan Dai, Jihuang Hu and Zhijian Yang	**525**	Inverse photoemission studies of the Si(100)2 × 1 surface
R Schneider, H Dürr, Th Fauster and V Dose	**528**	The temperature dependence of the inverse photoemission from copper surfaces
H S Chauhan, L Ilver, P O Nilsson, J Kanski and U O Karlsson	**531**	The electronic structure of Cd(0001) as studied by photoemission, inverse photoemission and computations
A G Eguiluz, W Hanke, P Gies and M Heinrichsmeier	**533**	Non-local exchange-correlation potential at a metal surface from many-body perturbation theory
F Finocchi, C M Bertoni and S Ossicini	**535**	Simple metal surfaces and image potential states
F Máca, M Said, K Kambe and M Scheffler	**538**	Electronic structure and angular resolved photoemission calculations for fcc and bcc silver surfaces

J E Inglesfield	**543**	Electric fields and surface electronic structure
K Edamoto, E Miyazaki and H Kato	**547**	Angle-resolved photoemission study of NbC(111) surface
E Pehlke, D Samuelsen and W Schattke	**550**	Calculation of photoemission spectra for 1T–$TiSe_2$ and 1T–TiS_2
A R Law, P T Andrews and H P Hughes	**553**	An inverse photoemission study of vanadium diselenide
T Greber, St Büchler and L Schlapbach	**556**	Growth of Yb layers on Pd, PdH_x and Al studied by 3d core level spectroscopy using SiK_α radiation
H B Nielsen, U Burghaus, G Broström and E Matthias	**558**	Electronic structure of K on Ag(100)
T Yasue, A Ichimiya and S Ohtani	**561**	Electron stimulated desorption from hydrogen and alkali adsorbed Si(111) surface
G R Castro, P Pervan, E G Michel, R Miranda and K Wandelt	**564**	Interaction of potassium with Si(100)2 × 1
C A Papageorgopoulos and M Kamaratos	**567**	Adsorption of K on clean and hydrogenated Si(100)2 × 1
P Soukiassian, T Kendelewicz, S T Kim, C A Papageorgopoulos, S Kapoor, Y Baros and Z D Hurych	**571**	Chemisorption of alkali metals (Na, K, Cs) on Ge(111) surface
L Reining and R Del Sole	**575**	Screened Coulomb interaction at a semiconductor surface
C A Papageorgopoulos, J Cousty and R Riwan	**578**	Cs adsorption on Si(100)2 × 1
A Kiejna	**580**	Work function of K and Rb submonolayers adsorbed on Al(111) and Mg(0001)
G V Hansson	**583**	Electronic structure of Si and Ge surfaces and $Si/Si_{1-x}Ge_x$ heterojunctions studied with photoelectron spectroscopy
H Carstensen, T Holdmann, R Claessen, R Manzke and M Skibowski	**588**	Momentum resolved electronic band gaps of III–V semiconductor (110) surfaces
G Cox, K H Graf, D Szynka, U Poppe and K Urban	**591**	Observation of point defects and microfaceting on GaAs(110) surfaces by Scanning Tunneling Microscopy
H Wormeester and E G Keim	**596**	Atomic nature of '5 × 1' reconstructed Si(110) as revealed by chemical titration with N_2O and O_2: AES and LEED results
A Mazur and J Pollmann	**600**	Mean-square displacements at the reconstructed Si(001)–(2 × 1) surface
W S Verwoerd and P Badziag	**602**	Structure and energetics of Ge(111)c(2 × 8) reconstruction
P Ruggerone, P Santini, L Miglio and G Benedek	**605**	Lattice dynamics of GaAs(110) and Ge(111): 2 × 1
L Kipp, C Janowitz, G Mante, H P Barnscheidt, J Olde, R Manzke and M Skibowski	**608**	Occupied and unoccupied electronic states of GaAs($\bar{1}\bar{1}\bar{1}$) (2 × 2)
Hua Qu, J Kanski, P O Nilsson and U O Karlsson	**610**	Valence bands and surface states of CdTe(110): a new surface resonance in the $\bar{\Gamma}\bar{X}$ azimuth
S Sawada	**612**	New tight-binding model of silicon for theoretical studies of surfaces
L Barbier and J Lapujoulade	**615**	Study by thermal energy atom scattering of the reconstructions of the Si(100) surface
G Petö, E Kótai and J Kanski	**618**	Surface regrowth of implantation damaged Ge(111)
M Abraham, G LeLay and J Hila	**621**	Reversible phase transitions on clean Ge surfaces studied by ellipsometry
C M J Wijers and G P M Poppe	**624**	Anisotropic off-normal incidence optical reflection from GaP(110) surfaces

B Hellsing	**628**	Electronic mechanism for alkali-metal promoted dissociation of oxygen on semiconductors
S Nishigaki, S Matsuda, T Sasaki, N Kawanishi, H Takeda and A Kawase	**632**	Potassium and oxygen adsorption on Si(100): local charge states probed with helium metastables
E Landemark, L S O Johansson, C J Karlsson and R I G Uhrberg	**635**	Surface electronic structure of clean and hydrogen chemisorbed Ge(100)2 × 1 studied by angle-resolved photoemission
P Krüger and J Pollmann	**638**	Adsorption of sulfur on Ge(001): first-principles calculation of structural and electronic properties
A A Karpushin, Yu O Kanter, A N Sorokin and Yu A Fomichev	**640**	Formation of the 'ionic part' in the Si–Si bond of chemisorbed Si overlayers on metallic terminated GaAs(100) and InAs(100) surfaces
S Valeri, M Lolli and G Ottaviani	**643**	GaAs and InP surface behaviour under ion bombardment, alkali deposition and oxygen exposure
P J Sebastian and V Sivaramakrishnan	**647**	Oxygen adsorption on the surface of CdSe(x)Te (1–x) thin films
T Hanada and M Kawai	**650**	Surface structure and oxidation of Si(001)–Bi
Th Schedel, K-H Frank, U Karlsson and E E Koch	**652**	Orientation of tetracene as a large hydrocarbon on Si(111)-(7 × 7) and oxidized Si(111)
W Ranke, X H Chen and E Schröder-Bergen	**656**	Adsorption and dissociation of NO on germanium
S Nannarone, S D'Addato, M G Betti, U del Pennino, Yu Chen, P Samonto and G J Lapeyre	**660**	HREELS investigation of clean and hydrogen-InP(110) surfaces
C M Bertoni, M Buongiorno Nardelli and E Molinari	**663**	Hydrogen adsorption on compound semiconductor surfaces
F Bartels and W Mönch	**667**	Oxidation mechanism of III–V semiconductors
A Berger, D Troost and W Mönch	**669**	Adsorption of atomic nitrogen at GaAs(110) surfaces
A P Mowbray and R G Jones	**672**	The adsorption and desorption of iodine on InSb(001)
S Rossi Salmagne, H-U Baier and W Mönch	**676**	NH_3-induced surface states and dipoles of InP(110) surfaces
H I Starnberg, P Soukiassian and Z Hurych	**678**	Alkali metal promoted oxidation of semiconductors: oxidation kinetics
S Ossicini, O Bisi and C M Bertoni	**681**	The electronic properties of Si-$NiSi_2$(111) epitaxial interfaces
Y Borensztein, R Alameh, T Lopez-Rios and W Q Zheng	**684**	Optical study of Ag overlayers deposited on Si(111)-7 × 7 as a function of temperature
D Vandré, L Incoccia and G Kaindl	**687**	Formation of the Mg–Si(111) interface studied by surface EXAFS
C C Hsu, Baoqui Li and Sunan Ding	**690**	Electronic properties of the Cr–Si(111) interfaces
F Manghi and C Calandra	**693**	Theoretical investigation of the Fermi level pinning at the Sb–GaAs(110) interface
G Annovi, M G Betti, U del Pennino and C Mariani	**695**	High resolution electron energy loss spectroscopy study of the Sb–GaAs(110) system
P Althainz, U Myler and K Jacobi	**699**	Gallium Schottky-barrier formation of Si(113)
J Y Veuillen, T T Nguyen, R Cinti, S D'Addato, S Turchini, S Nannarone, A Santaniello and G Rossi	**702**	BIS investigation of Pd–Si(111)7 × 7 interface formation
J Fogelberg, H Dannetun, I Lundström and L-G Petersson	**705**	A hydrogen sensitive palladium metal-oxide-semiconductor device as sensor for dissociating NO in H_2-atmospheres
J R Hayes	**709**	Impact of new material technologies on device design

M Jaros, P J Hagon and K B Wong	**712**	Microscopic theory of heterojunctions
M Nishio, H Ogawa and A Yoshida	**715**	Low-pressure MOCVD growth of ZnTe and observation of gas reaction
F Houzay, J M Moison, C Licoppe and Y I Nissim	**718**	Thermal and photon-assisted interaction of ammonia, silane and oxygen with indium phosphide substrates
P Guyot-Sionnest and A Tadjeddine	**720**	Non-linear optical response at the metal–single crystal electrolyte interface
I Kelson	**723**	Nuclear delayed desorption—preliminary results and potential applications

EXTENDED ABSTRACTS

A Nilsson, H Antonsson and N Mårtensson	**725**	Electronic structure of adsorbates from core level shake up spectra: CO and N_2 on Ni(100)
P Chocianowski	**726**	The investigation of oxygen adsorption on Nb(110): work function measurements
M G Ramsey, G Rosina, H H Graen and F P Netzer	**726**	Ordered organic overlayers on Pd(110): aniline and phenol
A Klekamp, G Brosig and E Umbach	**728**	Adsorption screening dynamics, and stimulated dissociation of SF_6 on Ni(111)
N Memmel, G Rangelov, E Bertel and V Dose	**729**	Two-dimensional unoccupied band structure of CO on Ni(110) and Pd(110)
C Schneider, H-P Steinrück, T Pache, P A Heimann, D J Coulman, E Umbach and D Menzel	**730**	A comparative study of the electronic structure of CO, CO + K, NO and NO + K on Ni(111) by ARUPS using synchrotron radiation
G R Castro, H Conrad, G Doyen, M E Grillo, R Hemmen and H Isern	**731**	Combined experimental and theoretical study of CO on NiAl(110)
E Fridell, B Hellsing, B Kasemo, S Ljungström, A Rosén and T Wahnström	**732**	Determination of the activation energy for OH desorption in the catalytic $H_2 + O_2$ reaction on Pt
K Wagemann, X R Chen, U Näher and J Wanner	**733**	Dynamics of CuF desorption in the etching reaction of fluorine with single-crystal copper surfaces
N Kruse, G Abend and J H Block	**734**	Kinetics of surface reactions on the atomic scale: NO on stepped rhodium single crystal surfaces
F Zaera, H Hoffman and P R Griffiths	**735**	Isolation and surface reactions of ethyl groups on Pt(111): a RAIRS, TPD and XPS study
R Imbihl, A E Reynolds and D Kaletta	**736**	Computer simulation of the reaction-induced faceting of Pt(110) in $CO + O_2$
S A Joyce, J A Yarmoff, T E Madey and P Nordlander	**738**	The influence of adsorbed potassium on electron stimulated desorption of PF_3 on Ru(0001)
A Winkler and K D Rendulic	**739**	Influence of surface defects on thermal desorption spectra
R E Palmer, E T Jensen and P J Rous	**740**	Resonance electronic excitation in electron scattering from oriented O_2 on graphite
M Pedio, L Becker, B Hillert, S D'Addato and J Haase	**741**	NEXAFS of the p(2 × 2) and ($\sqrt{3} \times \sqrt{3}$)R 30°-O–Ni(111) systems: a multiple scattering analysis
K D Rendulic, G Anger and A Winkler	**742**	Adsorption and desorption kinetics in the systems H_2–Cu(111), H_2–Cu(110) and H_2–Cu(100)
H Dabringhaus and H J Meyer	**743**	Interaction of molecular beams of alkali halides with (100) surfaces of alkali halide crystals
H F Berger, G Anger, S Feistritzer, A Winkler and K D Rendulic	**744**	Microfacets of the (1 × 2) reconstructed Pt(110) surface seen in the adsorption dynamics of hydrogen

J P Vigneron, M Scheffler, Th Laloyaux, I Derycke and A A Lucas	**745**	Spatial electron current distribution in a scanning tunneling microscope
M Sokolowski and H Pfnür	**747**	Step-induced changes of critical properties of oxygen p(2 × 2) on a stepped Ru(0001) surface
U Breuer, O Knauff and H P Bonzel	**748**	Investigation of the temperature-dependent surface order on Pb(110) by X-ray photoelectron diffraction
B Salanon and J Lapujoulade	**748**	A generalization of the gaussian approximation for the analysis of diffraction data from rough surfaces
T Honda, T Okano and Y Tuzi	**750**	Surface diffusion of Ga atoms on Ge(100) plane studied by autocorrelation analysis of field-emitted electrons
T Rodach, K P Bohnen and K M Ho	**751**	First principles study of the Cu(100), Cu(110) and the Cu(111) surface
P Zeppenfeld, U Becher, K Kern, R David and G Comsa	**752**	On the structure and dynamics of thin Ar films on Pt(111)
P Dubot, E Alleno, M-G Barthés-Labrousse, C Binns and C Norris	**753**	Valence changes in low dimensional Sm films adsorbed on Cr(211) and (110) surfaces
H Poppa	**754**	Nucleation and cluster size in ultra-thin metal deposits
K Starke, K Ertl, M Donath and V Dose	**755**	Exchange splitting of bulk and surface states on Ni(001)
S Schuppler, N Fischer, E Bertel and W Steinmann	**755**	Two-photon photoemission on Ni(111) image states
P A Huttunen, D T Britton, J Mäkinen, E Soininen and A Vehanen	**756**	Thermalized positron reflection at the surface potential
K O Magnusson and B Reihl	**757**	Inverse and direct photoemission from alkali/semiconductor interfaces
G Hincelin and T Lopez-Rios	**758**	Photoemission yields of cesium on silver surfaces
A I Shkrebtii, R Del Sole, C M Bertoni and B A Nesterenko	**759**	The atomic structures of reconstructed Si(110) surface phases
W Ranke	**761**	Structure of Si and Ge surfaces in the orientation range (001)–(115)–(113)
M Tikhov, G Rangelov and L Surnev	**763**	The interaction of oxygen with Na-covered Si(100)2 × 1
A El Khalki, F Proix and C A Sébenne	**764**	Effects of ionised nitrogen on the surface properties of GaAs(110)
C Wigren, J N Andersen, R Nyholm and U O Karlsson	**764**	Electron spectroscopy studies of the initial ytterbium–silicon interface formation
A Tulke, H Lüth, J Leiber, A Brauers and P Balk	**765**	Passivation of III–V semiconductor surfaces using arsenic layers and double layers of phosphorus and arsenic deposited by plasma MOCVD
AUTHOR INDEX	**767**	

numbers 4–6

Selected Proceedings of the
11th INTERNATIONAL VACUUM CONGRESS (IVC-11)
7th INTERNATIONAL CONFERENCE ON SOLID SURFACES (ICSS-7)
25–29 September 1989, Cologne, FRG

Plenary Lecture

C W Chu	**773**	High temperature superconductivity in bulk and film

Electronic Materials and Processing

G Bomchil	**781**	Silicon-on-Insulator: materials aspects and technological applications
A L Vazquez de Parga, C Ocal, J E Ortega and R Miranda	**784**	Local characterization of ultrathin oxides on silicon wafers by scanning tunneling microscopy
G R Castro, P Pervan, E G Michel, R Miranda and K Wandelt	**787**	Local versus non-local character of the alkali-promoted oxidation of silicon
G W Rubloff, B Nielsen, K G Lynn, D O Welch and T C Leung	**790**	Microvoids and defect chemistry at the $Si-SiO_2$ interface studied by positron annihilation depth profiling
C Heimlich, M Kubota, Y Murata, T Hattori, M Morita and T Ohmi	**793**	ARUPS study of an impurity-induced stabilization of SiO_2 on Si(100)
Y C Du, H Wang, B Z Li, D C Sun, Z Q Yu and F M Li	**796**	Rapid formation of ultra-thin dielectrics by Si surface modification using a large area low energy electron beam
W Jaegermann, C Pettenkofer and B A Parkinson	**800**	Ag on p-WSe_2(0001) surfaces: approaching the Schottky limit?
Zs J Horváth	**804**	The effect of the metal–semiconductor interface on the barrier height in GaAs Schottky junctions
J B B Oliveira, C A Olivieri, J C Galzerani, A A Pasa, L P Cardoso and F C de Prince	**807**	Characterization of AuGeNi ohmic contacts on n-GaAs using electrical measurements, Auger electron spectroscopy and X-ray diffractometry
W Pletschen and K H Bachem	**811**	Influence of plasma and ion beams on the electrical properties of n-GaAs Schottky diodes
W A Henle, M G Ramsey and F P Netzer	**814**	The formation of the Gd–Si(111)7 × 7 interface and the enhanced oxidation of Si: a study with AES, EELS and LEED
M S Stojanović, F Boreli, K Subotić, M Milosavljević and Z Milosević	**818**	The influence of the surface treatment and edge protection on the noise level in Au–Si surface barrier gamma detectors
V I Belyi, N P Sysoeva and B A Kolesov	**821**	Removal of elemental arsenic by water from the GaAs surface
C Achete	**824**	Interdiffusion and compound formation in the Au–Pd–Si thin film system
K Solt	**827**	Characterization of amorphous PtSi Schottky contacts on Si
M Milosavljević, N Bibić, M Stojanović, J Turković and I H Wilson	**831**	Thermal diffusion in Au–WTi–Pd metallization on silicon
Th Chassé, M Alonso, R Cimino, K Horn and W Braun	**835**	Indium interaction with GaP(110): example of an unreacted interface
Da Teng and Weihua Zhuang	**839**	Transverse photocurrent spectra of GaAs–AlGaAs multiple quantum wells
M Benyezzar, D King, P L Jones and D Moore	**842**	Preparation of zinc sulphoselenide alloys using MBE
M Barkai, E Grünbaum and G Deutscher	**847**	The epitaxial growth on CaF_2 and BaF_2 single-crystal films on a sapphire substrate
S Bensalah, J-P Lacharme and C A Sébenne	**851**	p-Type overdoping at clean Si(111) surfaces upon vacuum annealing
S Chaudhuri, A Dhar and A K Pal	**853**	Studies of some wide band gap II–VI semiconductor based p–n junctions
R Lenhard and S Luby	**856**	Investigation of defects in boron implanted silicon by means of p–n junction
H-U Habermeier, G Mertens and G Wagner	**859**	*In situ* preparation of superconducting Y–Ba–Cu–O thin films on bare silicon

J Lensink, C F J Flipse, K Heeck, R Griessen and B Dam	**862**	Low temperature fluxline relaxation effects in $YBa_2Cu_3O_{7-\delta}$ thin films
K Setsune, S Hayashi, H Adachi, K Hirochi, S Kohiki, S Hatta and K Wasa	**864**	Superconducting thin films of n-type copper oxide prepared by rf magnetron sputtering
S Athavale, O Auciello, M Bourham, O E Hankins, A Gras-Marti, J C Moreno-Marin and J A Valles-Abarca	**867**	Transport processes in plasma assisted deposition of superconducting thin films
A Gauzzi, H J Mathieu, J H James and B Kellett	**870**	AES, XPS and SIMS characterization of $YBa_2Cu_3O_7$ superconducting high T_c thin films
H Nakamura, M Hirai, M Kusaka and M Iwami	**875**	Electronic and atomic structure of a Co silicide–Si contact system
F Braunschweig and R Lochner	**878**	Application of a chemical trap to an aluminium/chlorine etching process
M L Hitchman	**880**	Low pressure chemical vapour deposition—some considerations, some models, some insights
H Kawarada, Y Yokota, Y Mori, A Tomiyama, J S Ma, J Wei, J Suzuki and A Hiraki	**885**	Luminescence and semiconducting properties of plasma CVD diamond
I Yamada	**889**	Thin film preparations by low energy ion beams
F Ringeisen, M Alaoui, D Bolmont and J J Koulmann	**892**	Room temperature disilane adsorption on Si(111) and Ge(111) studied by UPS: a comparative study
M Pichot	**895**	Dry processing in microelectronics: towards low pressure plasma technology
A M Barklund, H-O Blom, S Berg and L Bardos	**899**	Patterning of silicon wafers using the plasma jet dry etching technique
Yu E Babanov, A V Prokaznikov and V B Svetovoy	**902**	Influence of the surface electron processes on the kinetics of silicon etching by fluorine atoms
P Van Daele, D Lootens and P Demeester	**906**	Dry etching of III–V semiconductors: influence of substrate temperature on the anisotropy and induced damage
S M Francis, P A Goulding and M E Pemble	**909**	A comparative study of the adsorption of CH_2Cl_2, CH_3I and CH_2I_2 on GaAs(100) surfaces at 300 K
V Craciun, I N Mihailescu, I Ursu, G Leggieri, A Luches, M Martino and E Radiotis	**912**	One-step surface implantation and reaction by laser irradiation of multistructures deposited on Si and Ge samples
N Sugiyama, T Isu, T Kamijoh, Y Kajikawa and Y Katayama	**915**	Atomic layer growth of GaAs by molecular beam epitaxy using desorption of excess Ga atoms
A Bosacchi, S Franchi, Yu O Kanter and S I Chikichev	**919**	GaAs MBE growth under Ga-rich conditions studied by RHEED intensity oscillations
G J Davies, E G Scott, M H Lyons and M A Z Rejman-Greene	**923**	Multi-quantum well modulator arrays fabricated by gas source MBE
Da Teng, Weihua Zhuang, Jiben Liang and Yuzhang Li	**926**	Photoreflectance and photoluminescence characterization of GaAs grown on Si
H Kibbel and E Kasper	**929**	Industrial aspects of silicon molecular beam epitaxy
M Ichikawa and T Doi	**933**	Observation of electromigration effect upon Si-MBE growth on Si(001) surface
B V King, M Katayama, M Aono, R S Daley and R S Williams	**938**	Analysis of CaF_2–Si(111) using coaxial impact–collison ion scattering spectroscopy
L Incoccia, S Cramm, I Storjohann, F Senf and C Kunz	**941**	NEXAFS and photoemission investigation of the initial step of epitaxial growth of CaF_2–Si(111)

N Guerfi, T A Nguyen Tan, J Y Veuillen and R Cinti	**943**	Interface formation and epitaxy of CaF_2 on $CoSi_2(111)$–Si(111)
M A Gell, M H Herman, I D Ward, C J Gibbings, M E Jones, C G Tuppen, A C Churchill and P C Klipstein	**947**	e-Beam electroreflectance of short-period Si–Ge superlattices
T R Gow, F Lee, R Lin, A L Backman and R I Masel	**951**	The decomposition of trimethylgallium, triethylgallium and trimethylaluminum on Si(100)
A J Murrell, A T S Wee, D H Fairbrother, N K Singh, J S Foord, G J Davies and D A Andrews	**955**	The thermal decomposition of triethylgallium on GaAs(100)
J Nishizawa and T Kurabayashi	**958**	Mechanism of gallium arsenide MOCVD
W Richter	**963**	Mechanisms and results in MOVPE
A Watanabe, T Kamijoh, M Hata, T Isu and Y Katayama	**965**	The mechanism of atomic layer epitaxy of GaAs using trimethylgallium and arsine
A T S Wee, A J Murrell, N K Singh, D M O'Hare and J S Foord	**968**	Surface decomposition mechanism of the novel precursor bistrimethylamine aluminium hydride on GaAs(100)
D S Buhaenko, S M Francis, P A Goulding and M E Pemble	**972**	The adsorption of triethylgallium on GaAs(100) at 300 K
R Strümpler, R Compañó Monte and H Lüth	**975**	Decomposition of diethylarsine on Si(100) surfaces: a HREELS study
D E Aspnes, E Colas, A A Studna, R Bhat, M A Koza and V G Keramidas	**978**	Kinetic limits to growth on (001) and (110)GaAs by OMCVD
C Calandra, F Manghi and T Minerva	**982**	Oxygen-induced surface states in $YBa_2Cu_3O_7$
R Claessen, T Buslaps, G Mante, R Manzke, M Skibowski and J Fink	**986**	Surface electronic structure of the 83 K superconductor $Bi_2Sr_2CaCu_2O_8$
V A Gasparov, A F Dite, V V Bondarev, S F Kondakov, I M Ovchinnikov, N M Sorokin, S S Khasanov and V G Yaremenko	**989**	*In situ* surface investigations of $YBa_2Cu_3O_{7-x}$ epitaxial and Bi–Ca–Sr–Cu–O oriented films
S Nakanishi, N Fukuoka, K Nakahigashi, M Kogachi, H Sasakura, S Minamigawa, Y Mizokawa and A Yanase	**992**	Behavior of Pb deposited on single crystal surface of Bi–Sr–Ca–Cu–O
J Matsui	**996**	Use of synchrotron radiation for X-ray lithography and semiconductor materials characterization
S Baunack and A Zehe	**1003**	Electron beam-induced decomposition of MBE grown CaF_2 films: an AES study
E Weissman and Y Shapira	**1006**	Photoemission efficiency and persistence of (Cs, F) and (Cs, O) activated GaAs(110)
Y Rosenwaks, Y Shapira and D Huppert	**1009**	Surface recombination velocity of CdS($11\bar{2}0$) interfaces with metals
A Nemcsics, L Petrás and K Somogyi	**1012**	Observation of dislocations in GaAs by (photo)-electrochemical method
L J Brillson, S Chang, J Shaw and R E Viturro	**1016**	Interface states at metal–compound semiconductor junctions

C Stephens, D R T Zahn, R Cimino, W Braun, K Fives and I T McGovern	**1021**	A photoemission study of the Bi–InP(110) interface
M Alonso, R Cimino, K Horn, Th Chassé and W Braun	**1025**	Temperature-dependent interface formation study of aluminium on GaP(110)
J M Molarius, K Morishita, E Kolawa and M-A Nicolet	**1029**	Encapsulation of GaAs and GaAs–Pd in furnace annealing
P Russer	**1033**	Millimeterwave silicon devices
R Pretorius	**1038**	Phase sequence of silicide formation at metal–silicon interfaces
X Wallart, J P Nys, H S Zeng and G Dalmai	**1043**	Correlation between electrical and microscopic properties of Ti–Si interfaces
M Iwami, M Hirai, M Kusaka, H Nakamura, H Watabe and F Akao	**1046**	Soft X-ray spectroscopy (SXS) study of electronic and atomic structures of a Ni silicide–Si system
K Radermacher, S Mantl and K Kohlhof	**1049**	The influence of the substrate temperature on the formation of buried epitaxial $CoSi_2$ by ion implantation

EXTENDED ABSTRACTS

J S Resh, K D Jamison, J Strozier, A Bensaoula and A Ignatiev	**1052**	Phase differences in RHEED oscillations of various beams during epitaxial growth of GaAs(100) by MBE
S P da Cunha, M Schreiner, C I Z Mammana, A P Mammana and R Landers	**1053**	SnO_2–Si(100) interface
W M Arnold Bik, R N H Linssen, F H P M Habraken, W F van der Weg and A E T Kuiper	**1055**	Diffusion of hydrogen in low pressure chemical vapour deposited silicon nitride films
L J Whitman, S A Joyce, J A Yarmoff, F R McFeely and L J Terminello	**1056**	The chemisorption of $SiCl_4$, Si_2Cl_6, and chlorine on Si(111)7 × 7
K D Jamison, A Bensaoula, H D Shih and A Ignatiev	**1057**	Electrical and structural properties of InSb(111) epitaxially grown on Al_2O_3(0001)
G S Dong, Chunhui Huang, X K Lu, P Chen and Xun Wang	**1058**	Surface properties of $Al_{0.07}Ga_{0.3}As$(100) studied by XPS and ARUPS
K Kodama, M Ozeki, K Mochizuki, Y Sakuma and N Ohtsuka	**1060**	X-ray photoemission spectroscopy studies of III–V compounds prepared by atomic layer epitaxy
X Jin, M Y Mao, Y S Luo, G S Dong, P Chen and X Wang	**1061**	The electronic structure of $(NH_4)_2S_x$ treated GaAs(100) surface studied by UPS and XPS
R Cimino, C Carbone and W Braun	**1062**	Role of interface gap states during the formation of the Fe–GaAs(110) Schottky barrier
M Hünermann, D Spaltmann, N Esser, U Resch and W Richter	**1063**	Structural properties of Bi on GaAs(110) and InP(110) studied by Raman spectroscopy and LEED
M Sancrotti, F Ciccacci, M Fanfoni and P Chiaradia	**1064**	Temperature-dependent Cu interface growth on GaP(110) via Auger lineshape and X-ray photoemission spectroscopies
L Duo, M Sancrotti, M Newell, P Weightman, D Norman, R Cosso, S D'Addato, A Ruocco and S Nannarone	**1065**	Yb interface growth on GaP(110): an electron spectroscopy investigation

Thin Films

A Wakahara, T Tsuchiya and A Yoshida	**1071**	Epitaxial layers of indium nitride by microwave-excited metalorganic vapor phase epitaxy

B Gelin, A M Barklund, C Nender and S Berg	**1074**	Patterning with the use of ion-assisted selective deposition
J-O Carlsson	**1077**	Novel and selective vapor deposition processes
K M Eisele, W Rothemund and B Dischler	**1081**	Photolytic silicon nitride deposition for gallium arsenide by 193 nm excimer laser radiation
D Schäfer, B Brauns, R Wolf, B Steiger and G Zscherpe	**1084**	Laser-assisted methods for deposition, diagnostics and modification of optical thin films
N Mikoshiba, J Murota and A Kohlhase	**1087**	Low-pressure chemical vapour deposition of silicon and germanium on silicon using contamination-minimized processing
M Krohn	**1091**	Atomic morphology of thin films in the early stages of growth
J L Robins and A D Gates	**1094**	Explaining the anomalous orientation of epitaxial gold on sodium chloride
S Bourgeois, D Devillard, T Guindet, F Jomard and A Steinbrunn	**1097**	Surface and interface study of molybdenum evaporated on NiO(100) surfaces
R Anton, A Schmidt and V Schünemann	**1099**	Heterogeneous nucleation of binary alloy particles
Z H Barber	**1102**	The growth of sputter-deposited silver–copper films
H Bludau, M Skottke, B Pennemann, P Mrozek and K Wandelt	**1106**	Growth of ultrathin Au and Ag films on a modified Ru surface
S Ozawa and Y Sasajima	**1109**	Computer experiments of initial growth kinetics of vacuum-deposited thin films
C A Stone and N M Ghoniem	**1111**	The effects of cluster size-dependent aggregation on thin film formation
Qin-lin Guo and P J Møller	**1114**	On the electronic structure of Cu ultra-thin film on α-Al_2O_3(0001) surfaces
B Vogt, B Schmiedeskamp and U Heinzmann	**1118**	Spin-resolved core and valence electron photoemission from non-epitaxially grown Pb layers on Pt(111)
M-A Hasan, G Radnoczi and J-E Sundgren	**1121**	Epitaxial growth of Al on Si(100) and Si(111) by evaporation in uhv
L Kubler, F Lutz, J L Bischoff and D Bolmont	**1124**	Substrate temperature-induced changeover from homogeneous to step nucleated growth modes for the initial thermal oxidation of Si(001) by O_2
G Pető, T Lohner, L Pogány and T Andersson	**1128**	Thickness dependent migration of Au films
M Azizan, T A Nguyen Tan and J Y Veuillen	**1132**	First stage of the formation of refractory metal thin films on Si(111)
P Habig and R Riedinger	**1135**	Angular resolved photoemission of thick chromium epitaxially grown on a FeSi(001) surface
T Kimura, S Yamamura, K Koike, T Morita, S Yugo and T Kamiya	**1138**	The mechanism for photoconductive response of B-implanted and annealed InGaAs layers
Quan-De Wu, Xu Zhang and Zeng-Quan Xue	**1141**	Spectral response of Ag–Cs_xO thin films
A Temmink, O Anderson, K Bange, H Hantsche and X Yu	**1144**	4f level shifts of tungsten and colouration state of a-WO_3
R Thielsch, W Meiling and E Göring	**1147**	Structural, optical and electronical properties of mixed dielectric films

A Cachard, R Fillit, I Kadad and J C Pommier	**1151**	Magnetron sputtering deposited AlN waveguides: effect of the structure on optical properties
K Tominaga	**1154**	Preparation of AlN films by planar magnetron sputtering system with facing two targets
Y Nakanishi, H Ohshima, Y Suzuki, Y Fukuda and G Shimaoka	**1157**	The structural changes in the oxide films of tin caused by oxidation
S Klahn, P Hansen and F J A M Greidanus	**1160**	Recent advances in thin films for magneto-optic recording
D Weller and W Reim	**1166**	Anomalous valence and structural changes in intermetallic $Yb_x(FeCo)_{1-x}$ films
Y Wang, J Jiao and W Wang	**1170**	Determination of partial RDF for Gd–Fe amorphous film by X-ray anomalous scattering
C Sella, J C Martin and P Gadenne	**1172**	Structure and optical properties of Au–Cr sputtered films used in digital optical recording media
B Cord and W Maaß	**1176**	Sputtered magnetic films for rigid disk production
B Kramer	**1179**	Quantum transport in thin films and inversion layers
A Carl, G Dumpich and E F Wassermann	**1183**	Incipient Anderson Localization in thin Pd_xC_{1-x} mixture films
M D Tillin and J R Sambles	**1186**	Temperature dependence of surface plasmon–polaritons on silver
R Huber and P Ziemann	**1189**	On the T^2-dependence of the electrical resistivity of Pd and Pd–H films
C Marliere	**1192**	Quantum size effect detected by work function measurements during indium deposition on polycrystalline, texturized gold substrate
A Carl, G Dumpich and E F Wassermann	**1195**	Magnetoresistance of thin inhomogeneous gold films
Y Sato	**1198**	Characterization of thermally oxidized iridium oxide films
Y Teraoka	**1201**	Magnetism of transition metal thin films with a nearly half-filled d band
Chen Guoping, Li Lingzhen, Zhang Suixin and Zhang Haokang	**1204**	Structures and properties of a Ta_2O_5 thin film deposited by dc magnetron reactive sputtering in a pure O_2 atmosphere
V A Gasparov, V A Grazhulis, V V Bondarev, T M Bychkova, V G Lifshits, B K Churusov, N G Galkin and N I Plusnin	**1207**	Electrophysical properties of the surface phases of In and Cr on Si(111)
K Sumiyama	**1211**	Structural, magnetic and electronic properties of non-equilibrium Fe–Ag alloys
J L Sacedon, J Avila, M Fernandez, P Fort and J P Terrat	**1215**	Contact resistance and surface composition of N-doped Al films
L Lechevallier, G Richon, J Le Bas and M Bernole	**1218**	Structure and ohmic behaviour of gold–chromium thin films obtained by controlled coevaporation
K Komorita	**1221**	Electrical behavior of a Bi_2O_3 thin film planar-type device
T Kajiwara, T Urakabe, K Sano, K Fukuyama, K Watanabe, S Baba, T Nakano and A Kinbara	**1224**	Mechanical and electrical properties of rf sputtered LaB_6 thin films on glass substrates
K Sato, C Y Chang, A Patrinos, R W Vook and J A Schwarz	**1229**	Combined resistance and temperature change measurement for the study of electromigration

J Birch, Y Yamamoto, L Hultman, G Radnoczi, J-E Sundgren and L R Wallenberg	**1231**	Growth and structural characterization of single-crystal (001) oriented Mo–V superlattices
M Sakurai, J Fujita, K Yamashita, K Ohtani, I Hatsukade, K Tamura, H Nagata, Y Suzuki and S Seki	**1234**	Characterization of multilayer reflectors for the soft X-ray region using synchrotron radiation
K H Huang, M G Blamire and R E Somekh	**1237**	A resistometric study of Nb/Ta single-crystal superlattices
J Barnaś, A Fuss, R E Camley, U Walz, P Grünberg and W Zinn	**1241**	Layered magnetic structures: magnetoresistance due to antiparallel alignment
D G de Groot, A J Vermeer, C W Hagen, T A M Schröder, N J Koeman, J H Rector, R Griessen, M G Karkut, J M Triscone and Ø Fischer	**1244**	Critical currents in superconducting Mo/V and Nb/Pd multilayers
C Sella, M Kaabouchi, R Krishnan and M Naili	**1247**	Microstructural and magnetic characterization of the interfaces in Ni/C and Co/C multilayers
A Maeda, T Satake, T Fujimori and H Kuroda	**1251**	Structural and magnetic characteristics of Eu/Mn and Eu/Yb superlattices prepared by the MBE technique
A Yamama, T Ito and A Hiraki	**1254**	Silicidation of patterned narrow area of porous silicon
K Sugioka and K Toyoda	**1258**	Properties of Cu thin films formed selectively on *n*-GaAs by projection patterned laser doping
Jiann-Ruey Chen, Li-Di Chang and Fon-Shan Yeh	**1261**	Interface reaction of Pt–(111)Si with the substrate at 450°C
Zhang Yichen, Yang Naiheng and Pang Shijin	**1264**	Formation of Ag single-crystalline thin films by ion implantation with $N^+ : Xe^+$
F Edelman, E Y Gutmanas and R Brener	**1268**	Solid state reactions and diffusion processes in metal–Si_3N_4–Si thin film systems—a comparison between Cr, Co and Ni metals
P Panjan, A Žabkar, B Navinšek, V Kraševec, V Marinković, Dj Mandrino, M Godec, M Maček and A Zalar	**1272**	Characterization of multilayer structures with titanium nitride and titanium silicide
Y Claesson, N Wassdahl, M Georgson, G Bray, C-G Ribbing and J Nordgren	**1275**	Monitoring of thin film sputtering by soft X-ray emission spectroscopy
R Abermann	**1279**	Measurements of the intrinsic stress in thin metal films
G S Blackman, C M Mate and M R Philpott	**1283**	Atomic force microscope studies of lubricant films on solid surfaces
F R Brotzen, C T Rosenmayer, C G Cofer and R J Gale	**1287**	Creep of thin metallic films
M Fryda, K Taube and C-P Klages	**1291**	Nanometer indentation measurements on metal-containing amorphous hydrogenated carbon films (Me–C : H)
G Keller, R Erz, I Barzen, M Weiler, K Jung and H Ehrhardt	**1294**	Mechanical properties, structure and composition of ion-plated tungsten carbide films
S Kuroda, T Fukushima and S Kitahara	**1297**	Generation mechanisms of residual stresses in plasma-sprayed coatings
G Thurner and R Abermann	**1300**	On the mechanical properties of uhv-deposited Cr films and their dependence on substrate temperature, oxygen pressure and substrate material

H Hornauer, J Patrikos and K Röll	**1302**	Sensor head for measurement of stress anisotropy in thin films
S Scaglione, L Caneve and G Emiliani	**1305**	Mechanical properties of coated copper mirrors
G K Wolf, M Barth, W Ensinger and M Hans	**1308**	Ion beam-assisted deposition for low temperature formation of coatings
M D Adamiker, X Cai, A Wagendristel, H Bangert and P Torzitzky	**1310**	FEM-simulation of damage in coated samples caused by wedge-shaped bodies
D Paulmier and H Zaidi	**1314**	The friction coefficent of hydrogenated surfaces of polycrystalline graphite
S Söderberg, A Gerendas and M Sjöstrand	**1317**	Factors influencing the adhesion of diamond coatings on cutting tools
G Reiss	**1322**	STM on polycrystalline thin films
G Krausch, R Platzer, U Wöhrmann, X L Ding, R Fink, B Luckscheiter, J Voigt, R Wesche and G Schatz	**1325**	Interface compound formation in Ni/In thin film couples
J Verhoeven, H Zeijlemaker, E J Puik and M J van der Wiel	**1327**	On the use of H^+ and Ar^+ ions for high spatial resolution depth profiling
J A Jackman, T E Jackman, P Rousseau and L Weaver	**1330**	Recent applications of compositional depth profiling by secondary ion mass spectrometry
A M Edwards, M C Fairbanks, R J Newport and S J Gurman	**1335**	Structural studies of amorphous semiconductor–metal alloys
M Özenbaş	**1339**	Amorphous-to-crystalline transition of selenium thin films deposited onto aluminum substrates
N Blayo, B Drévillon and J Huc	**1343**	*In situ* infrared ellipsometry study of the vibrational properties, and the growth of amorphous semiconductor ultrathin films
J-E Sundgren	**1347**	Ion-assisted film growth: modification of structure and chemistry
N Cherief, J Y Veuillen, T A Nguyen Tan, R Cinti and J Derrien	**1350**	Formation of the Fe-stepped Si(100) interface as studied by electron spectroscopy
B Kebabi, C Khan Malek and F R Ladan	**1353**	Stress and microstructure relationships in gold thin films
T R Anthony	**1356**	Metastable synthesis of diamond
X-D Pan, E A Maydell, R H Milne and D J Fabian	**1360**	Diamond-like carbon films prepared by rf plasma deposition
S Yugo, T Kimura and T Muto	**1364**	Effects of electric field on the growth of diamond by microwave plasma CVD
Y H Shing and F S Pool	**1368**	Electron cyclotron resonance deposition of diamond-like films
T Sugita, E Nishikawa, Y Yoshida, H Funamoto and O Koseki	**1371**	Pattern marking on synthetic diamond film by Penning discharge sputtering
D Ugolini, J Eitle and P Oelhafen	**1374**	Influence of process gas and deposition energy on the atomic and electronic structure of diamond-like (a-C : H) films
R Kleber, W Dworschak, J Gerber, A Fuchs, T Pütz, J Scherer, K Jung and H Ehrhardt	**1378**	Mechanical properties of hard a-C : H films
X Jiang, K Reichelt and B Stritzker	**1381**	The hardness and Young's modulus of a-C : H films

K Kobashi, T Inoue, H Tachibana, K Kumagai, K Miyata, K Nishimura and A Nakaue	**1383**	Selected-area deposition of diamond films
K Okano, T Kurosu, M Iida, T Eickhoff, H Wilhelm and D R T Zahn	**1387**	An optical investigation of diamond thin films on silicon
M A Silveira and A P Mammana	**1390**	Considerations on the design of a dc sputtering system concerning its application to Ta and Si deposition
M Mausbach, H Ehrich and K G Müller	**1393**	Cu and Zn films produced with an anodic vacuum arc
V B Penchev, V S Etarski and V I Valkov	**1396**	Electrical supply circuit for electron beam evaporators
P Muralt and J P Seidel	**1400**	Thin film sputter deposition for hybrid applications
A P Mammana, I L Torriani, M A Silveira and L A C de Almeida	**1403**	Characterization of Ta thin films obtained by dc sputtering
V Damodara Das and N Soundararajan	**1405**	Nature of principal scattering mechanism in well-annealed antimony thin films—analysis from thermoelectric data
A Heinrich, C Gladun, H Schreiber, J Schumann and H Vinzelberg	**1408**	Electrical properties of heterogeneous CrSi(O, N) thin films
P J Schmitz, W-Y Leung, G W Graham and P A Thiel	**1411**	Unexpected structure in Rh films on Ag(100): implications for magnetic films on noble-metal substrates
J Barnaś, M Zimpel and P Grünberg	**1414**	Interface magnetic and collective electronic modes in randomly layered metallic structures
E Becker, G Dumpich, C Meier, U Kirschbaum, E F Wassermann and W Kiauka	**1416**	Magnetic and structural behaviour of Fe/Ni and $Fe/Fe_{1-x}Ni_x$
Ming-cheng Wu, Qin-lin Guo and P J Møller	**1418**	Ultrathin films of CuCl on TiO_2(110): electronic structure and surface reconstruction
A Domenicucci and R W Vook	**1422**	Contact potential difference study of the growth of palladium on ⟨111⟩ fibre-textured aluminum thin films
C C Hsu, J Ho, J J Qian, Y T Wang and Y X Wang	**1425**	Lanthanum silicide formation in thin La–Si multilayer films
L Blossfeld, W L Larson, L Kammerdiner, B T Banko and C E Wickersham	**1428**	Ferroelectric $Pb(Zr,Ti)O_3$ thin films by reactive sputtering from a metallic target
Quan-De Wu	**1431**	Nucleation and growth of vapor phase deposition on solid surfaces
C Y Chang, V D Vankar, Y C Lee, R W Vook, A J Patrinos and J A Schwarz	**1434**	Electromigration studies using *in situ* TEM electrical resistance measurements
A Banovec, B Stariha, A Zalar, B Praček and M Kern	**1437**	AES depth profiling on ACTFEL structures
P Gröning, T Greber, J Osterwalder and L Schlapbach	**1439**	On the growth of a metallic Ce film on SiO_2
M Foster, M Stamm, G Reiter and S Hüttenbach	**1441**	X-ray reflectometer for study of polymer thin films and interfaces
H G Swamy, B S Naidu and P J Reddy	**1445**	Structure and optical properties of $CuGaSe_2$ thin films
Y S Murthy, B S Naidu and P J Reddy	**1448**	Optical absorption of single phase $AgGaSe_2$ thin films

R Rousina, G K Shivakumar and G H Yousefi	**1451**	Optical absorption of as-deposited indium selenide thin films
Y Nakanishi, T Suzuki, H Tatsuoka, H Kuwabara, H Fujiyasu, Y Fukuda and G Shimaoka	**1454**	Preparation of SrSe thin films by hot wall deposition
M Leskelä, L Niinistö, P Niemela, E Nykänen, P Soininen, M Tiitta and J Vähäkangas	**1457**	Preparation of lead sulfide thin films by the atomic layer epitaxy process
A K Pal, A Mondal and S Chaudhuri	**1460**	Preparation and characterization of ZnTe/CdSe solar cells
J Kanazawa, T Haranoh and K Matsumoto	**1463**	Effect of chemical state of doped Sn on the electrical properties of sputtered ITO films
P Boháč, L Jastrabík, D Chvostová and V Železný	**1466**	The optical properties of GeO_2, ZnS and Ge films produced by rf sputtering
J C Dudek and F Sabary	**1469**	Interpretation of optical absorption peaks in Ag granular films supported by an oxidized Al substrate
A Heilmann, C Hamann, G Kampfrath and V Hopfe	**1472**	Preparation and optical properties of plasma polymer silver composite films

EXTENDED ABSTRACTS

J Aarts, J Meiressonne, H Sprey, W Maj and P Zagwijn	**1476**	Proximity effect in superconducting multilayers
H Störi	**1477**	Tribological and protective coatings
T Sugita, E Nishikawa, S Ebisawa, Y Kamimura and S Hanashima	**1478**	A handy and miniature sputtering apparatus
A Santucci, S Beretta, G Reverberi, M Bellotto and F Parmigiani	**1479**	Optical and structural properties of e-beam evaporated TiO_{2-x} films

Fusion Technology

P Wienhold	**1483**	Wall conditioning techniques for fusion devices
J v Seggern, H Peters, H G Esser, P Wienhold and J Winter	**1486**	Composition of a-C/B:H films and of redeposited layers in the boronized TEXTOR tokamak
T Banno, P Wienhold, J Winter and F G Waelbroeck	**1489**	AES studies of redeposited impurities on samples exposed in the scrape-off layer of TEXTOR
S Michizono, T Banno and A Kinbara	**1493**	Hydrogen recycling in carbon films
F Fauser, D K Murdoch and P J Dinner	**1497**	Vacuum system concepts for NET and ITER
G Bonizzoni, A Conte, G Gatto, G Gervasini, F Ghezzi and M Rigamonti	**1500**	Tritium storage plant based on a combination of St707 and St737 getter alloy beds for high field fusion machines
G Bonizzoni, F Gnesotto, P Sonato and S Vitturi	**1503**	The vacuum and gas inlet systems for RFX fusion experiment
C Andelfinger, H Kollotzek, M Ulrich, G Weber and K H Bernhardt	**1508**	A centrifuge pellet injector for ASDEX upgrade
Y Oda, M Onozuka, T Shimomura, S Iwamoto, N Hashiri, S Kuribayashi, S Kasai, K Hasegawa, I Ishibori and Y Miura	**1510**	Development of repeating pneumatic pellet injector
E Usselmann, J L Hemmerich, D Holland, L Grobusch, U Schargitz, R Sartori and G Saibene	**1515**	Experimental set-up for gas balance measurement at JET

F L Tabares, B Garcia-Castañer, M Liniers, N Lorente, J Hackman and the TJ-I team **1519** Global particle balance in the TJ-I tokamak

G D Loesser, P Heitzenroeder, D Kungl, H F Dylla, G Böhme, M Selig and G Cerdan **1523** Remote maintenance of in-vessel components in Tokamak Fusion Test Reactor

R T McGrath **1528** Thermal loads on tokamak plasma-facing components during normal operation and disruptions

P Bonnel, P Chappuis and M Lipa **1540** Particle pumping in TORE SUPRA

S Adamson, M-L Apicella, A-P Martinelli, E Taglauer and the ASDEX team **1545** Collector probe measurements of metallic impurity fluxes in the divertor chamber of the ASDEX tokamak

K Akaishi, S Watanabe, M Asano, Y Kubota and A Miyahara **1549** A helium particle detector for the ALT-II pump limiter experiment

K Akaishi and T Kawamura **1552** Analysis of pump limiter action for particle removal from vacuum physics viewpoints

M S Agarwal, M K Radhakrishnan and A K Singh **1555** Application of vacuum arc in the study of unipolar arcs in tokamaks

N Itoh **1558** Synergistic effects in radiation-induced particle ejection from solid surfaces

Y Nakashima, K Yatsu, Y Kiwamoto, M Ichimura, K Tsuchiya, S Miyoshi, K Masuda, Y Koguchi, T Kai and T Sasaki **1561** Helium cryopumping system in the tandem mirror GAMMA 10

G Bonizzoni **1565** The vacuum and tritium systems for the fusion experiment Ignitor

EXTENDED ABSTRACT

E Gauthier, M H Achard, A Grosman and P Monier **1569** TORE SUPRA first wall conditioning

AUTHOR INDEX **1571**

numbers 7–9

Selected Proceedings of the
11th INTERNATIONAL VACUUM CONGRESS (IVC-11)
7th INTERNATIONAL CONFERENCE ON SOLID SURFACES (ICSS-7)
25–29 September 1989, Cologne, FRG

Applied Surface Science

V Wüstenhagen, M Schneider, J Taborski, W Weiss and E Umbach **1577** Concept and realization of a photon-induced scanning Auger microscope

S Mróz and B Stachnick **1581** Angular distribution of Auger electron emission from the (111) Ni face for particular energies in the Ni $M_{2,3}$ VV transition

S Tougaard, W Hetterich, A H Nielson and H S Hansen **1583** Non-destructive depth information by inelastic XPS/AES background analysis, application to Cu_2O growth investigations

J Finster, E-D Klinkenberg, J Heeg and W Braun **1586** ESCA and SEXAFS investigations of insulating materials for ULSI microelectronics

R Schmidt, G Wedler and P Wißmann	**1590**	Ellipsometric response to hydrogen adsorption on thin iron films
P G Coleman, J A Baker and N B Chilton	**1593**	Positron beam studies of doped Cz-grown silicon
Y Goldstein, O Millo and A Many	**1595**	Auger electron spectroscopy of adsorbed layers—quantitative analysis
R Levi-Setti	**1598**	Recent applications of high resolution secondary-ion-mass-spectrometry imaging microanalysis
M P Seah and G C Smith	**1601**	Quantitative AES and XPS: calibration of electron spectrometers for true spectral measurements—VAMAS round robins and parameters for reference spectral data banks
A Many, Y Goldstein, S Z Weisz and O Resto	**1605**	Effect of instrumental resolution on quantification in Auger electron spectroscopy measurements
Fan Chuizhen, Yang Dequan and Chen Yu	**1608**	A new consideration for matrix effects correction in quantitative AES analysis
R v Criegern	**1611**	Improved and new surface analysis and depth profiling methods for the analysis of semiconductor technology problems
L T Drzal	**1615**	The role of the fiber–matrix interphase on composite properties
I leR Strydom and S Hofmann	**1619**	XPS and EELS study of the valence band electronic structure of TiN and (Ti, Al)N coatings as influenced by the deposition parameters
A Barraud	**1624**	Chemical sensors based on LB films
J F Geiger, K D Schierbaum and W Göpel	**1629**	Surface spectroscopic studies on Pd-doped SnO_2
M G Cattania, P d'Antona, F Morazzoni and R Scotti	**1633**	Characterization of defects on ZnO and Ru–ZnO: a structural, TPD, and spectroscopic study
M Takeuchi, S Kashimura and S Ozawa	**1636**	Photoconductive and gas sensitive properties of ultrafine ZnO particle layers prepared by a gas evaporation technique
J Haber	**1638**	Solid surfaces as the scene of catalytic act
G Molnár, G Petö, E Kótai and L Guczi	**1640**	The oxidation of $Gd_{0.95}Si_{0.05}$ layers
R Fink, G Krausch, B Luckscheiter, R Platzer, J Voigt, R Wesche, U Wöhrmann, X L Ding and G Schatz	**1643**	Diffusion of isolated In atoms on Ag and Cu surfaces
J Reif, P Tepper, J C Zink, B Wassermann, S Mirbt and E Matthias	**1646**	Second harmonic generation on alkali halide surface: evidence for polarized water adsorption
W R Salaneck, N Sato, R Lazzaroni and M Lögdlund	**1648**	Electronic and chemical structure of conjugated polymer 'surfaces'
H van der Wel, A H M Sondag, L Postma and R C C Roberts	**1651**	A combined TOF SIMS and FTIR MSR study on the analysis of several polyimide surfaces
O Ganschow, R Jede and U Kaiser	**1654**	Progress in solids analysis by sputtered neutral mass spectrometry
B Schueler, P Sander and D A Reed	**1661**	A time-of-flight secondary ion microscope
D G Welkie, S Daiser and C H Becker	**1665**	Prospects for quantitative chemical mapping of surfaces using the 'Surface Analysis by Laser Ionization' (SALI) technique

S Kaesdorf, H Schröder and K L Kompa	**1669**	Aspects of quantification of off-resonance laser ionization for SNMS
R G Emery, B V King and R J MacDonald	**1671**	Low energy ion beam mixing of aluminium impurity multilayers
M-P Macht, R Willecke and V Naundorf	**1674**	Depth resolution for sputter sectioning of Ni
C Gatts and W Losch	**1676**	Analysis of multi-layered structures by a non-conventional Auger depth profiling method
Ming Lu, Qiang-Ji Zhang and Lu Fei	**1680**	Analysis of Ta_2O_5–Ta interface
N Usuki	**1683**	Photoelectron spectroscopic study of copper surfaces changed by oxygen ion bombardment
C H de Villeneuve, M Phaner, L Porte, N Monocoffre, P Pertosa and J Tousset	**1686**	Topographic modifications on the graphite surface induced by high energy single-ion impact
J Dekker, H J W Zandvliet and A van Silfhout	**1690**	Low energy ion bombardment on c-Ge surfaces
Yongxue Li, Runsheng Zhai and Xiexian Guo	**1692**	Ion scattering spectroscopy with low energy He^+ ions applied to measure the coverages of several simple gases on Rh(111)
E Adem, R Champaneria and P Coxon	**1695**	Escascope — a new imaging photoelectron spectrometer
O Anderson	**1700**	Deconvolution of UPS and XPS spectra
T Lang, A Tschulik, H Laimer and H Störi	**1703**	Quantitative Auger spectroscopy of titanium nitrides by means of factor analysis
F Marchetti, M Dapor, S Girardi, M Cipparrone and P Tiscione	**1706**	Auger quantitative analysis and preferential sputtering in brass alloys
H S Hansen and S Tougaard	**1710**	Quantitative analysis of the Au–Ni(111) system by XPS: separation of peaks and background subtraction
L Libioulle, M Taborelli and M Renier	**1714**	Mechanical stability of a STM junction
Tong Linsu, Cui Zheng and Mao Fuming	**1716**	A new type of combined bipole deflector for a rf glow discharge ion source
V Smolar	**1718**	Electron backscattering and penetration in the small-angle and transport approximation model
G M Mikhailov, V I Rubtsov and S A Orlov	**1721**	Inelastic scattering of middle-energy electrons by solid surfaces
A P Alexeyev and V I Zaporozchenko	**1725**	Quantitative depth analysis of impurities in solids based on combination of AES and EPMA
A Hofmann, P Streubel and A Meisel	**1728**	Soft X-ray photoelectron spectroscopy studies of the initial oxidation of $Al_xGa_{1-x}As(100)$ surfaces
M Hamagaki, S Kato, T Hara and S Hayashi	**1730**	SNMS—SNART: focusing on insulator analysis
Cha Liangzhen, A Adnot and M Baril	**1733**	A study of secondary ion emission from silicon under improved experimental conditions
U Schily and J Heitbaum	**1736**	Reaction of clean lithium with O_2, SO_2 and liquid $LiAlCl_4 \cdot 3(SO_2)$, an XPS and Auger analysis
J P Kemp, D J Beal, P A Cox and J S Foord	**1739**	Surface segregation and sodium transport in Na_xCoO_2
F Morito	**1743**	AES analysis of grain boundary segregation and precipitation in electron beam welded molybdenum and Mo–0.56% Nb alloy

P E Viljoen and J P Roux	**1746**	Oxidation of a Au + 4 at% Ti alloy
E Than, H Podlesak and G Leonhardt	**1750**	On the relations between atomic interface parameters and the wettability and stability in metal–ceramic systems
Huairong Gao and Qing-Bin Lu	**1753**	Investigation of electron emission stability of negative electron affinity cathodes
M Murko-Jezovšek, B Praček, F Brecelj and L Nagy	**1756**	Investigation of contact surfaces and protective gas atmosphere in reed switches
S Yamamoto, I Watanabe, S Sasaki and T Yaguchi	**1759**	Work function and microstructure of a monoatomic order surface layer grown on a ($W-Sc_2W_3O_{12}$)-coated impregnated cathode
S Kimura, D Miyazaki, M Hara and M Fujiwara	**1763**	Emission characteristics and surface composition of dispenser cathodes in realistic vacuum
E Nowicka, Z Wolfram and R Duś	**1766**	Weakly bound hydrogen state on thin iron films
S Takeda	**1769**	High response humidity sensors with plasma polymerized organic film
A Dekanski, N S Marinković, J Stevanović, V M Jovanović, Z Laušević and M Laušević	**1772**	Properties of glassy carbon modified by immersing in metal cation solutions
I P Jain, Y K Vijay and R Chandra	**1776**	Ultra high vacuum depth selective conversion electron Mössbauer spectroscopy

EXTENDED ABSTRACTS

J F van der Veen	**1781**	Surface X-ray scattering during MBE crystal growth
P A Huttunen, J Mäkinen and A Vehanen	**1782**	Heteroepitaxial structures studied with positrons
M Prutton, M M El Gomati and P G Kenny	**1783**	Multispectral surface analytical microscopy
W Storm, M Altebockwinkel, L Wiedmann and A Benninghoven	**1785**	The influence of bombardment energy on preferential sputtering and depth profile analysis of mercury cadmium telluride (MCT) with SNMS, AES and XPS
M Altebockwinkel, W Storm, L Wiedmann and A Benninghoven	**1787**	Depth profile measurements of Pt_xSi_{1-x} layers by combined SIMS, SNMS, AES and XPS
S Ichimura, H Shimizu, K Kokuban, H Hashizume and K Goto	**1788**	A new ion counting system for laser sputtered neutral mass spectrometry
H Oppolzer	**1789**	Transmission electron microscopy of layered structures and interfaces
S Hofmann, W Hösler and R von Criegern	**1790**	AES depth profiling of Ta–Si multilayers: dependence of depth resolution of Ar^+ ion energy and incidence angle
T Koshikawa, H Nakamura, T Uchiyama, T Katayama, K Takagi, H Yamakawa, S Matsuura and E Inuzuka	**1791**	Low dose and high resolution measurements using two-dimensional position sensitive detector with medium energy ion scattering
G Chiarello, M Bellotto, F Curcio, M Musci, M Notaro and N Ricci	**1792**	Surface characterization of laser-produced SiC powders by means of XPS and XAES measurements
A I Kovalev, V P Mishina, G V Stsherbedinsky and D L Wainstein	**1794**	EELFS method for investigation of equilibrium segregations on surfaces in steel and alloys
U Zimmermann, G Schnitzler, M Schneider, M Kaiser, R Herde, V Wüstenhagen, J Taborski, N Karl, R Dudde, E-E Koch and E Umbach	**1795**	Monolayer adsorption and thin film growth of big aromatic molecules on Si(111)

Vacuum Science

W Jitschin, J K Migwi and G Grosse	**1799**	Gauge calibration in the high and medium vacuum range by a series expansion standard
T Mitsui and T Shigehara	**1802**	Application of metal–insulator–metal thin films as cold cathodes to the Bayard–Alpert gauge
C D Suen, J Z Chen and Y H Kuo	**1805**	An axial-emission bent beam gauge
P J Szwemin	**1807**	The influence of the external circuit on the ionization gauge stability
P M Strubin, N Fietier and S Vossiniotis	**1810**	Requirements for, and experience with, the vacuum controls during commissioning of the LEP uhv-system
M H Hablanian	**1814**	Design and performance of oil-free pumps
E Bez and D G Guarnaccia	**1819**	Operational experience with totally oil-free rough vacuum pumps
H-D Bürger, E Rossmanith, J-M Crinquette and M Taberlet	**1822**	Multistage dry pumps
P Bachmann and M Kuhn	**1825**	Evaluation of dry pumps vs rotary vane pumps in aluminum etching
H-P Berges and M Kuhn	**1828**	Handling of particles in forevacuum pumps
T Sawada and M Nakamura	**1833**	Spiral grooved visco-vacuum pumps with various groove shapes
H Yamakawa, Y Matsui, K Yui and H Yanagida	**1837**	Development of a bakeable cryopump for extreme high vacuum
H-U Häfner, H-H Klein and U Timm	**1840**	New methods and investigations for regenerating refrigerator cryopumps
H Yamakawa, I Moriyama, Y Minamigawa, Y Maeba, T Takematsu, M Nishitsuji, O Fujiki, T Asaishi and T Koike	**1843**	Contamination-free transfer of silicon wafers with a magnetic levitation transport system in vacuum
G Strasser, H P Bader and M Bader	**1846**	Contamination control in vacuum systems: venting and pumping
R G Brown, S Ormson, I Munro, A Troup and S A Collett	**1849**	A proposal for the partial pressure measurement of oil molecules by fluorescence spectroscopy
Z Hulek, Z Cespiro, R Salomonovic, M Setvak and J Voltr	**1853**	Measurement of oil deposit resulting from backstreaming in a diffusion pump system by proton elastic scattering
M Audi	**1856**	An ion pump based leak detector
Cha Liangzhen	**1860**	Theoretical and experimental studies of a platinum wire-glass standard leak
W Große Bley	**1863**	Temperature dependence and long term behaviour of capillary-type helium reference leaks with gas reservoir
A Miyahara	**1866**	Overview on new materials for vacuum techniques
Y J Pei, D M Jiang, W M Li and X Q Wang	**1870**	A new magnetic material with low outgassing rate for the electron storage ring of HESYRL
M Tosa and K Yoshihara	**1873**	Surface precipitation of boron nitride on the surface of stainless steel/boron nitride film
K Okada and M Yoshida	**1876**	New self-lubricating aluminum alloy base composites for vacuum technology
M Lefrançois, J Montuclard and C Rouaud	**1879**	Low-load metal seals to replace elastomer O-rings: the Helicoflex-delta (Δ) seals

LEP Vacuum Group	**1882**	LEP vacuum system: present status
R Ballion, J Boster, W Giesske, H Hartwig, D Jagnow, R Kose, J Kouptsidis, G Schumann and M Schwartz	**1887**	The vacuum system of the HERA electron storage ring
A P Kaan, G Luijckx, J H M Bijleveld, J A Heemskerk, J Touw and H Boer Rookhuizen	**1890**	The vacuum system of the Amsterdam Pulse Stretcher ring, AmPS
P A P Gomes, A R B de Castro and A R D Rodrigues	**1893**	Vacuum system of the VUV source of the Brazilian Synchrotron Light Laboratory
K Chida and A Mizobuchi	**1896**	Vacuum system of TARN II
J C Schuchman	**1899**	Vacuum system design for a superconducting X-ray lithography light source
H C Hseuh	**1903**	The AGS Booster vacuum systems
Y Hori and M Kobayashi	**1907**	Non-evaporable getter performance in the Photon Factory electron storage ring
A Pace and A Poncet	**1910**	Monte Carlo simulations of molecular gas flow: some applications in accelerator vacuum technology using a versatile personal computer program
J P Bacher and N Hilleret	**1914**	Corrosion of accelerator vacuum systems: risks and prevention
J-C Brunet	**1917**	Industrial fabrication of uhv quadrupole chambers for LEP
W Unterlerchner	**1920**	Non-standard vacuum hardware for an accelerator vacuum system
K M Welch, G T McIntyre, J E Tuozzolo, R Skelton, D J Pate and S M Gill	**1924**	Metal and elastomer seal tests for accelerator applications
S Ueda, M Matsumoto, T Kobari, T Ikeguchi, M Kobayashi and Y Hori	**1928**	Photodesorption from stainless steel, aluminum alloy and oxygen free copper test chambers
T A Heppell	**1931**	UHV pumping equipment and the expanding field of uhv activity
E Giorgi, C Boffito and M Bolognesi	**1935**	A new Ti-based non-evaporable getter
F Meli, Z Sheng, I Vedel and L Schlapbach	**1938**	XPS analysis of the getter mechanism and getter activation process
T Kikuchi, N Ohsako and Y Hayashi	**1941**	Capability of obtaining extreme high vacuum by commercial G–M refrigerator-cooled cryopump
Y C Liu, W J Lin and J R Chen	**1944**	The study of an aluminum-alloy distributed ion pump
I Kusunoki, H Satomi, M Kobori and H Domeki	**1946**	Stepping motor for use in uhv
Y Hayashi and T Yamada	**1948**	Development of the harmonic drive rotary feedthrough
T S Fountain and J R Stokoe	**1951**	Automation of all-metal uhv valves by compact actuator
G A Boiko, B I Medovar, L G Puzrin and M G Atroshenko	**1954**	Autovacuum and its application for product cladding
A Bubenzer and J P M Schmitt	**1957**	Plasma processes under vacuum conditions
Y Funato, K Akaishi, Y Kubota, T Tuzuki and A Miyahara	**1962**	Electron behaviour in cylindrical magnetron sputtering source
A Lunk	**1965**	Plasma activated physical vapour deposition (PAPVD) by hollow cathode arc (HCA)

R Kukla, T Krug, R Ludwig and K Wilmes	**1968**	A highest rate self-sputtering magnetron source
M Koshinaka, H Fujii, K Nakanishi and Y Shibuya	**1971**	Fabrication of AlN thin films by reactive ionized cluster beam deposition technique
M Moradi, C Nender, H-O Blom and S Berg	**1974**	Dynamic modeling of the process control of reactive sputtering
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Jiang Zengkui, Li Yunqi and Wang Baoxia	**1980**	Experimental study of $I-V$ characteristics of dc magnetron sputtering sources
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T Winkel and J Orchard	**1988**	Leak evaluation in JET and its consequences for future fusion machines
T Abe, Y Murakami, K Hikida, H Ohsawa and S Hata	**1992**	Development of ceramic turbomolecular pumps for fusion devices
Y Ishikawa and K Odaka	**1995**	Reduction of outgassing from stainless surfaces by surface oxidation
S Kato, H Oyama and H Odagiri	**1998**	Surface modification of vacuum wall by carbon and its outgassing
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Y Tuzi, T Okano and K Terada	**2004**	Accuracy of the conductance modulation method for the measurement of pumping speed and outgassing rate
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M Mühloff and H-P Kabelitz	**2018**	High vacuum pumps according to Holweck principle for semiconductor production
M De Simon	**2021**	Influence of clearances on turbomolecular pump performance
C Urano, H Kotaka, H Enosawa and K Obokata	**2025**	Resistance of turbomolecular pump to gallium
M Kuhn and P Bachmann	**2028**	Demands for turbo-molecular pumps in the aluminium etching process
J C Thomaz Jr, C V Speller and R A Douglas	**2032**	Experimental study of forced oscillations in the Orbitron
M Ota and N Hirayama	**2035**	Reactor-characteristics parameters for low pressure CVD processes
T Tachiwaki, M Muraoka, K Sawada and H Uyeha	**2038**	Estimation of sublimation rate from ice disk on heating plate at low pressures

G Reich	**2041**	On the significance of mean free path to vacuum physics and technology
R A Haefer and P Kleber	**2045**	Vacuum in space—an isotropic regime?
G Lewin	**2048**	How to characterize the vacuum environment
W Buschbeck, U Hoechner and W Schwarz	**2050**	Measurement of conductances of models in the molecular and viscous flow regime
G Reich	**2053**	Determination of the (pl) value based on the measurement of viscosity and thermal conductivity in the transition region
M Drechsler, A Claverie and J Chazelas	**2055**	Vacuum micro-chambers in electron microscopes
P Vijendran	**2058**	Status of vacuum industry in India
K S Sadykov and S A Figurov	**2061**	Investigation of diffusion pumps
F J Eckle, R Lachenmann and G Rüster	**2064**	Diaphragm pumps down to 2 mbar and their application in nuclear physics
D C Ba, N H Yang, X D Wang, S J Pang and Y Zhu	**2067**	The helical channel pumping mechanism of compound molecular pumps
J Y Tu, Y Zhu, X Z Wang and S J Pang	**2070**	The optimization design for turbo blades of a hybrid-type molecular pump
G H Li and S Xu	**2073**	New research on re-outgassing of SIP
T Murashita, T Kaneko, H Yoshihara and T Kitayama	**2076**	A Si single crystal photon-absorber for a compact SR ring
J R Chen, G S Chen, D J Wang, G Y Hsiung and Y C Liu	**2079**	An aluminum vacuum chamber for the bending magnet of the SRRC synchrotron light source
T Wikberg and E Dodelin	**2082**	FEM calculations of uhv all-metal demountable joints for LEP
B A Trickett, C Burnside, G Le Flem, D Schmied and E M Williams	**2086**	Effects of high energy synchrotron radiation at copper surfaces
M Bergoglio, A Calcatelli, M Plassa and P Chen	**2089**	Gas adsorption/desorption and materials stability
M Hirata and M Ono	**2093**	Pressure dependence of the sensitivity of a triode gauge
H D Bürger, K Handke and F Braunschweig	**2096**	Application of spiromolecular pumps in helium leak detection
Y Nagai, S Sakai, Y Saito, N Matuda and G Horikoshi	**2100**	Mass spectrometric observation of vacuum treated oxygen free copper
W K Huber, N Müller and G Rettinghaus	**2103**	Total and partial pressure measurement in the low 10^{-12} mbar range
J Koprio, P Muralt, G Rettinghaus and G Strasser	**2106**	Mass spectrometric detection of low-ppm contaminants in sputter process systems at 10^{-2} mbar, using a directly exposed ion source
R Dobrozemsky	**2109**	Calibration of vacuum systems by gas quantities
G W Schwarzinger	**2112**	Measurement of diffusion data in small samples
J Šetina	**2115**	The effect of housing tubes on the zero stability of spinning rotor gauges
R Stocker	**2118**	The quartz tuning fork as a total pressure gauge: a versatile concept

G Grosse, W Jitschin and D Wandrey	**2120**	Procedures for measuring pumping speeds
L Füstöss	**2123**	Molecular flow in composite systems and the resonance concept
G Hummer, G Halter and M Grössl	**2126**	Calculated and measured flow conductance for butterfly valves
P T Krasuski	**2129**	Gas flux distributions from cylindrical tubes in molecular flow
G Horikoshi, Y Saito and K Kakihara	**2132**	An analysis of a complex network of vacuum components and its application
H J Dittus and A M Schomisch	**2135**	Vacuum systems for microgravity experiments

EXTENDED ABSTRACTS

R N Peacock and N T Peacock	**2139**	The effects of closed grid ends and emission current on the sensitivity of B–A gauges in the range 10^{-4} to 1 Pa
Shao Deshan and Li Wei	**2140**	A study of measuring characteristics of vibrating diaphragm gauges
H J Tiller and D Berg	**2141**	Scrubbing of Cl-containing plasma waste gases
L Lieszkovszky and A R Filippelli	**2142**	Performance studies of partial pressure analysers
A R Herman and G Balog	**2143**	Some information problems in the presentation of vacuum science data
T Kanaji, T Urano and S Hongo	**2144**	A preliminary study of the cascade static lens gauge
Li Wangkui, Liu Qiang and Lu Shiliang	**2145**	A dynamic flow calibration system with four-sphere construction
Liu Bingkun and Qian Jin	**2146**	Monte Carlo analysis in a refrigerator cryopump

Vacuum Metallurgy

G Scharf	**2151**	Trends and specific features of special metallurgical concepts in the German Democratic Republic
H R Harker	**2154**	Experience with large scale electron beam cold hearth melting (EBCHM)
H Stumpp, G Sick, H Pannen and W Dietrich	**2157**	Advanced melting and casting plants with the high power electron and plasma beam
G Georgiev, V Vasileva, T Nicolov, N Dimitrov and G Mladenov	**2161**	Refinement of Ti and Mo using electron beam melting
V G Glebovsky, V N Semenov and V V Lomeyko	**2165**	On the problem of growing tungsten single crystal tubes from the melt
U U Gomes, A G P de Silva and D G Pinatti	**2167**	Sintering of tantalum powder from aluminothermic reduction product
R Hack, F Kiefer, D Schuler and N Müller	**2171**	Monitoring of vacuum sintering furnace atmosphere with a quadrupole mass spectrometer
M Hohmann and S Jönsson	**2173**	Modern systems for production of high quality metal alloy powder
J Felba, K Friedel and K Przybecki	**2177**	Application of glow discharge electron gun to surface modification
M Bielawski and A Furmanek	**2181**	Thermal cycling of cast iron surface by electron beam fusion treatment

O Knotek, F Jungblut and R Breidenbach	**2184**	Magnetron-sputtered superhard coatings within the system Ti–B–C–N
A Zhunda	**2187**	Optimization of evaporation and sputtering devices through substrate heating parameter
R F Bunshah and C Deshpandey	**2190**	Plasma-assisted deposition techniques for hard coatings
K S Fancey and A Matthews	**2196**	Process effects in ion plating
H Wulff, A Lunk and R Basner	**2201**	Mechanical properties and structure of TiN coatings deposited at different ion energies and titanium flux rates
R Luthier and F Lévy	**2205**	TiAlON black decorative coatings deposited by magnetron sputtering
H-D Steffens and M Mack	**2209**	Present status of low pressure and atmospheric plasma spraying
D Paulmier, A Bouchoucha and H Zaidi	**2213**	Influence of the electrical current on wear in a sliding contact copper–chrome steel, and connection with the environment
Yu Lipin	**2217**	Vacuum arc coatings in low pressure atmosphere cases
H W Holleck	**2220**	Advanced concepts of PVD hard coatings
W Precht and F Sterma	**2223**	The influence of surface topography on the adhesion of a TiN layer as a hard coating on different materials
J Kadlec, V Hrubý and M Novák	**2226**	Influencing properties of high-speed cutting steel, ion-nitrided and subsequently coated
D Paulmier, A Bouchoucha and H Zaidi	**2230**	Wear mode of a copper wire during a sliding contact with copper/chrome steel: influence of oxygen
S Kadlec, J Musil, V Valvoda, W-D Münz, H Petersein and J Schroeder	**2233**	TiN films grown by reactive magnetron sputtering with enhanced ionization at low discharge pressures
A F Ilyuschenko and K St Petkov	**2239**	Evaluation of adhesive energy in the process of material formation by a method of thermo spraying
AUTHOR INDEX	**2243**	
VOLUME 41 TITLE PAGE, VOLUME CONTENTS AND AUTHOR INDEX	**I**	